

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,514,043 B2
APPLICATION NO. : 10/758325
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INVENTOR(S) : Jean-Pasca Viola et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 14; line 7:
Claim 15 should read as follows:

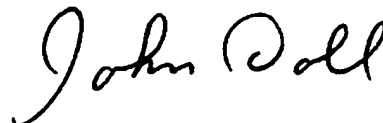
15. A kit for use in growing crystals by vapor diffusion, comprising a crystallization plate defining a plurality of wells pre-filled with a crystallization solution, at least one seal for sealing said wells with said crystallization solution contained therein, wherein said seal is made of a pierceable material for allowing individual holes to be defined in the pierceable material in order to permit vapor diffusion to occur separately for each of said wells, and wherein said seal extends across each of said wells to prevent the crystallization solution from contacting a crystallization surface associated with each of the wells.

Column 14; line 54:
Claim 26 should read as follows:

26. A method of making a pre-filled crystallization plate, comprising the steps of: providing a crystallization plate having a plurality of wells, dispensing a crystallization solution in the wells, individually sealing the crystallization solution in the wells by heat sealing a pierceable foil over the crystallization solution in the wells, and providing individual crystallization surfaces adapted to be sealingly associated with the wells, separately from the pierceable foil, to conduct individual crystallization experiments in the wells once the pierceable foils have been pierced.

Signed and Sealed this

Second Day of June, 2009



JOHN DOLL
Acting Director of the United States Patent and Trademark Office